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### Abstract

DNA is a promising candidate for nanoelectronics applications due to its customizable base sequence, low-cost replication, and selfassembly capabilities. While native DNA is a poor conductor and sensitive to environmental conditions, its conductivity and stability significantly improve when intercalated with metals, making it more robust and suitable for electronic integration.

# **Theory and Method**

**Density Functional Theory:** Used to calculate ground state energy (E) and Hamiltonian ( $H_0$ )

Transport

#### $T_{mn} = \Gamma_m G^r \Gamma_n (G^r)^{\dagger}$ , where $G^r = [EI - (H_0 + \Sigma_L + \Sigma_R + \Sigma_B)]^{-1}$ and $\Gamma_i(E) = -2Im(\Sigma_i)$

Here  $G^r$  is the retarded Green's function and  $\Sigma_{L/R}$ ,  $\Sigma_B$  are the self energy of left/right contacts and Buttiker probes respectively.

### **DNA as a device**

Electrical engineered devices an are arrangement of energy levels. • DNA offers stability, adjustable energy levels, self-organization, and programmability. Challenges Binding energies between bases ~ 100-130 meV in their native form Low electron hopping integral (10–100 meV)



#### **Energy Quantization** LUMO #4 0.1 LUMO #3 **Quantized Energy levels** $\psi|^2$ 0.2 T-Hg-T 0.1 Layers 0.0 0.3 LUMO #1 • Metalation of DNA induces quantized energy levels. 0.2 • LUMO probability density resembles the particle-in-0.1 13 7 1<sup>0.0</sup> Layers

eV)		10 <sup>1</sup>
E-E <sub>LUMO</sub> (eV)		10 <sup>0</sup>
ш Ш		10 <sup>-1</sup>
<b>(eV</b> )		10 <sup>-2</sup>
E-E <sub>HOMO</sub> (eV)		10 <sup>-3</sup>
Ц		

Layers DOS representing band bending (left) and superlattice (right)

## Conclusion

• Metal intercalation enhances the conductivity and stability of

• *Strong* transmission path is possible at the LUMO of T-Hg-T Electronic properties can be tailored: superlattices and band

It presents an engineered nanomaterial to probe molecular